

Features And Application

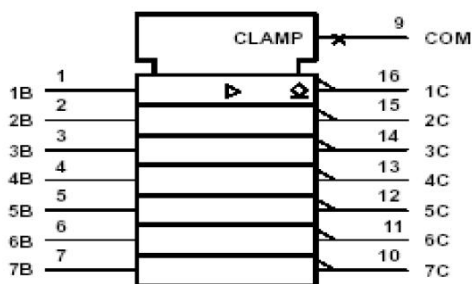
- 500-mA Rated Collector Current (Single Output)
- High-Voltage Outputs . . . 50 V
- Output Clamp Diodes
- Inputs Compatible With Various Types of Logic
- Relay Driver Applications

Description

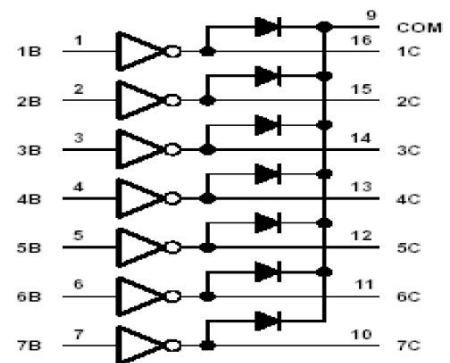
The CBM2003A are monolithic high-voltage, high-current Darlington transistor arrays. Each consists of seven n-p-n Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads. The collector-current rating of a single Darlington pair is 500 mA. The Darlington pairs may be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers.

The CBM2003A has a 2.7-k Ω series base resistor for each Darlington pair for operation directly with TTL or 5-V CMOS devices.

LOGIC SYMBOL



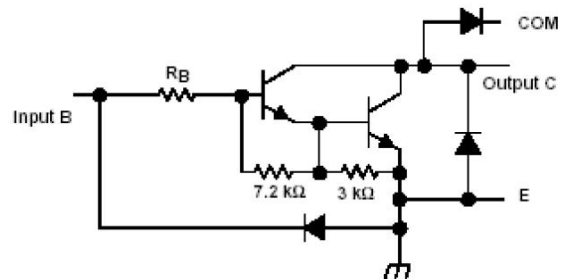
LOGIC DIAGRAM



SCHEMATICS (each Darlington Pair)

All resistor values shown are nominal.

CBM2003A: $R_B = 2.7\text{ k}\Omega$



Absolute Maximum Ratings (Ta =25°C)

| Parameter | Symbol | Limit Values | | Unit |
|-----------------------------|---------------|--------------|------|-------|
| | | Min. | Max. | |
| Output Sustaining Voltage | $V_{CE(SUS)}$ | -0.5 | 50 | V |
| Output Current | I_{OUT} | 500 | | mA/ch |
| Input Voltage | V_{IN} | - 0.5 | 30 | V |
| Clamp Diode Reverse Voltage | V_R | 50 | | V |
| Clamp Diode Forward Current | I_F | 500 | | mA |
| Power Dissipation | DIP | P_D | 1.15 | W |
| | SOP | | 0.95 | |
| Operating Temperature | T_{opr} | -40 | 85 | °C |
| Storage Temperature | T_{stg} | -55 | 150 | °C |

* Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied.

Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions(Ta= -40~85°C)

| Parameter | Symbol | Test Condition | Limit Value | | Unit | |
|-----------------------------|---------------|----------------|-------------------------------|------|------|-------|
| | | | Min | Max | | |
| Output Sustaining Voltage | $V_{CE(SUS)}$ | | 0 | 50 | V | |
| Output Current | DIP | I_{OUT} | TPW=25ms,Duty=10%, 7 Circuits | 0 | 370 | mA/ch |
| | | | TPW=25ms,Duty=30%, 7 Circuits | 0 | 200 | |
| | SOP | | TPW=25ms,Duty=10%, 7 Circuits | 0 | 390 | |
| | | | TPW=25ms,Duty=30%, 7 Circuits | 0 | 150 | |
| Input Voltage | V_{IN} | | 0 | 3. | V | |
| Clamp Diode Reverse Voltage | V_R | | | 50 | V | |
| Clamp Diode Forward Current | I_F | | | 400 | mA | |
| Power Dissipation | DIP | P_D | | 0.52 | W | |
| | SOP | | | 0.4 | | |

Electrical Characteristics ,Ta= 25°C (unless otherwise noted)

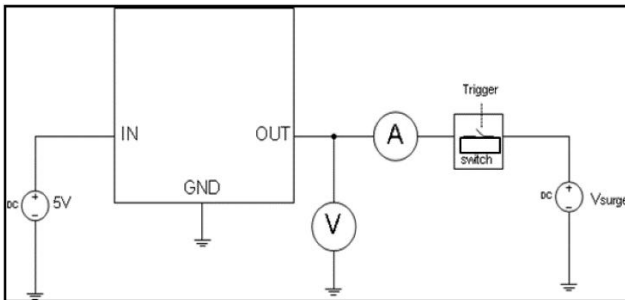
| Parameter | Test Fig. | Test Conditions | Min | Typ | Max | Unit | |
|---|-----------|--|-----------------------|-----|-----|------|---|
| V _{I(on)} On-state Input Voltage | 6 | V _{CE} =2V | I _C =125mA | | | | V |
| | | | I _C =200mA | | | 2.4 | |
| | | | I _C =250mA | | | 2.7 | |
| | | | I _C =275mA | | | | |
| | | | I _C =300mA | | | 3 | |
| | | | I _C =350mA | | | | |
| V _{CE(sat)} Collector-emitter saturation voltage | 5 | I _I =250uA I _C =100mA | | 0.9 | 1.1 | V | |
| | | I _I =350uA I _C =200mA | | 1 | 1.3 | | |
| | | I _I =500uA I _C =350mA | | 1.2 | 1.6 | | |
| I _{CEX} Collector outoff current | 1 | V _{CE} =50V I _I =0 | | | 50 | uA | |
| | 2 | V _{CE} =50V, I _I =0 T _A =85°C V _I =1V | | | 100 | | |
| h _{FE} DC Current Transfer Ratio | 5 | V _{CE} =2V, I _{OUT} =350mA | 1000 | | | | |
| V _F Clamp forward voltage | 8 | I _F =350mA | | 1.7 | 2 | V | |
| I _{I(off)} Off-state input current | 3 | V _{CE} =50V I _C =500uA T _A =85°C | 50 | 65 | | uA | |
| I _I Input current | 4 | V _I =2.4V | | 0.4 | 0.7 | mA | |
| | | V _I =5V | | | | | |
| | | V _I =12V | | | | | |
| I _R Clamp reverse current | 7 | V _R =50V | | | 50 | uA | |
| | | V _R =50V T _A =85°C | | | 100 | | |
| C _I Input capacitance | | V _I =0 f=1MHz | | 15 | 25 | pF | |

Switching Characteristics, TA=25°C

| Parameter | Test Conditions | Min | Typ | Max | Unit |
|--|---|--------------------|------|-----|------|
| t _{PLH} Propagation delay time, low-to-high-level output | See Figure 9 | | 0.25 | 1 | us |
| t _{PHL} Propagation delay time, high -to- low -level output | | | 0.25 | 1 | us |
| V _{OH} High-level output voltage after switching | V _S =50V, I _O =300mA, See Figure 10 | V _S -20 | | | mV |

* EOS (Electrical Over Stress) Immunity Level

Test Circuit



| Test conditions | |
|-----------------|--------|
| VCC | 12V |
| Power on time | 5000ms |
| Current max | 1.0A |
| IN | pin4 |
| OUT | pin13 |

tE (Endurance time) : time until IC damage / Criterion : IC should survive EOS

EOS Immunity Level: More than 5000ms

PARAMETER MEASUREMENT INFORMATION

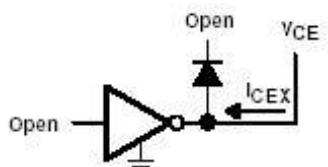


Figure 1. I_{CEX} Test Circuit

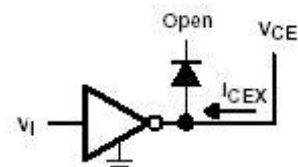


Figure 2. I_{CEX} Test Circuit

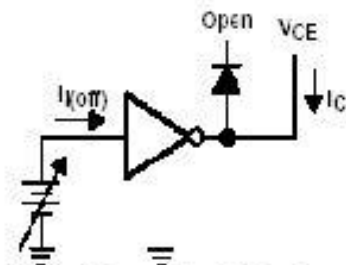


Figure 3. $I_{I(off)}$ Test Circuit

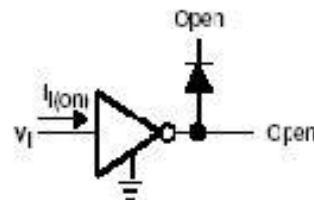
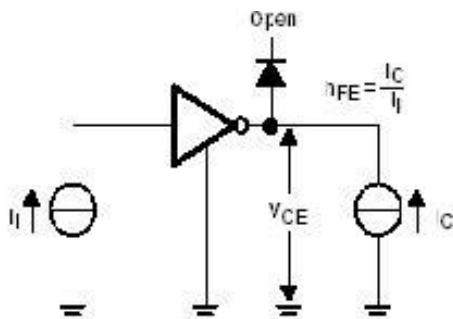


Figure 4. I_I Test Circuit



NOTE: I_I is fixed for measuring $V_{CE(sat)}$, variable for measuring h_{FE} .

Figure 5. h_{FE} $V_{CE(sat)}$ Test Circuit

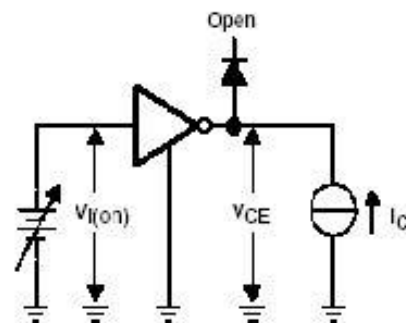


Figure 6. $V_{I(on)}$ Test Circuit

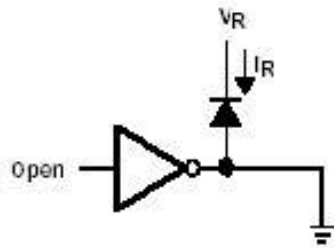


Figure 7. I_R Test Circuit

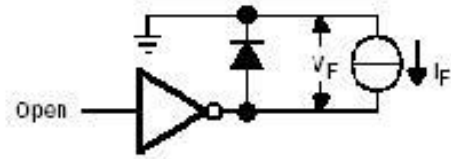


Figure 8. V_F Test Circuit

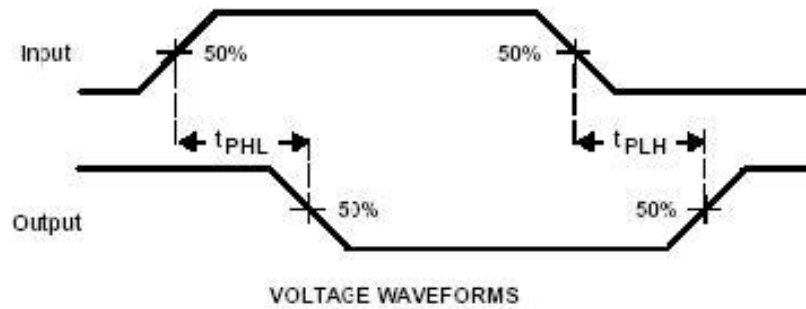


Figure 9. Propagation Delay-Time Waveforms

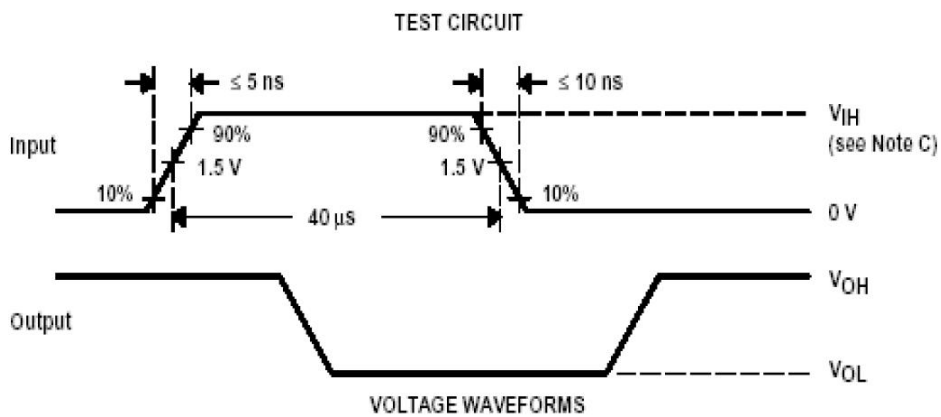


Figure 10. Latch-Up Test Circuit and Voltage Waveforms

- NOTES:**
- A. The pulse generator has the following characteristics: PRR = 12.5 kHz, $Z_O=50$.
 - B. CL includes probe and jig capacitance.
 - C. $V_{IH} = 3$ V;

TYPICAL CHARACTERISTICS

COLLECTOR-EMITTER
SATURATION VOLTAGE
VS
COLLECTOR CURRENT
(ONE DARLINGTON)

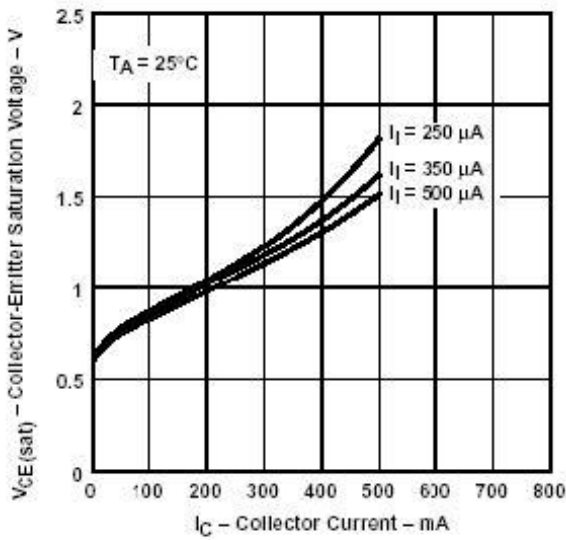


Figure 11

COLLECTOR-EMITTER
SATURATION VOLTAGE
VS
TOTAL COLLECTOR CURRENT
TWO DARLINGTONS PARALLELED

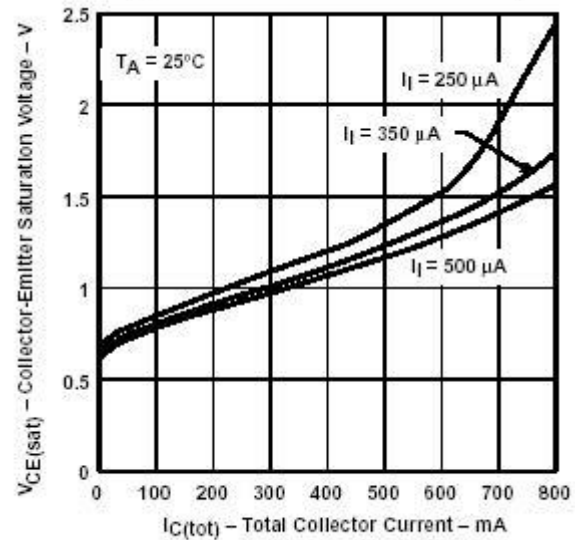


Figure 12

COLLECTOR CURRENT
VS
INPUT CURRENT

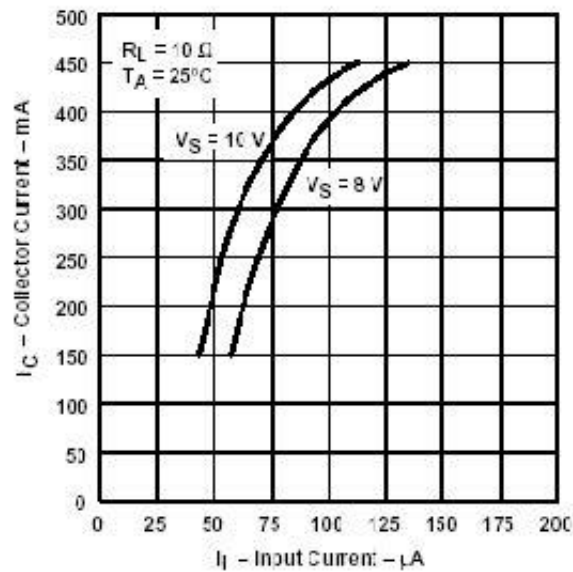


Figure 13

THERMAL INFORMATION

D PACKAGE
MAXIMUM COLLECTOR CURRENT
Vs
DUTY CYCLE

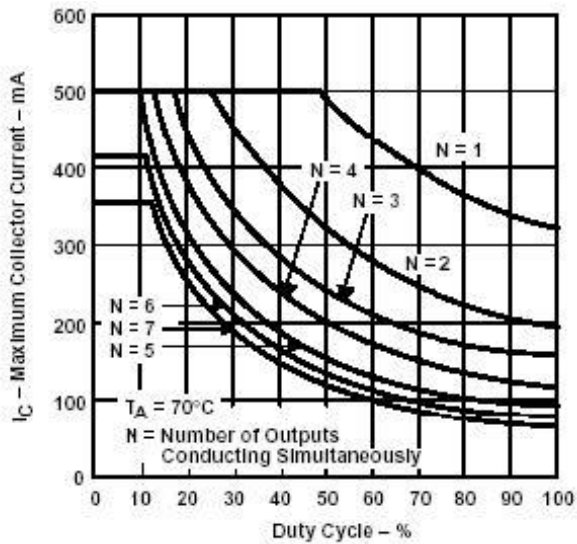


Figure 14

N PACKAGE
MAXIMUM COLLECTOR CURRENT
Vs
DUTY CYCLE

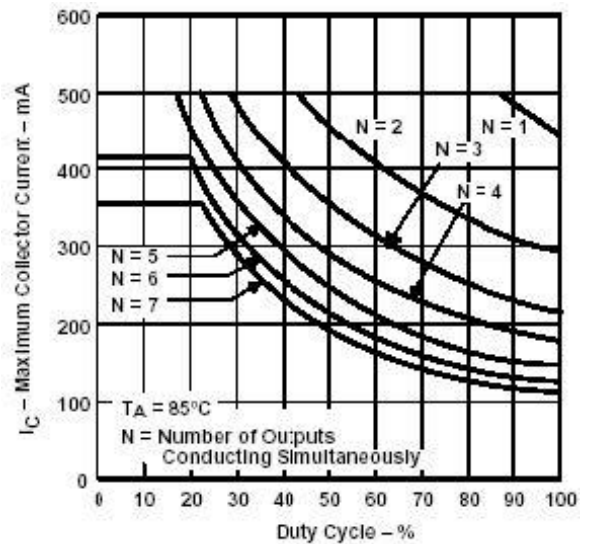
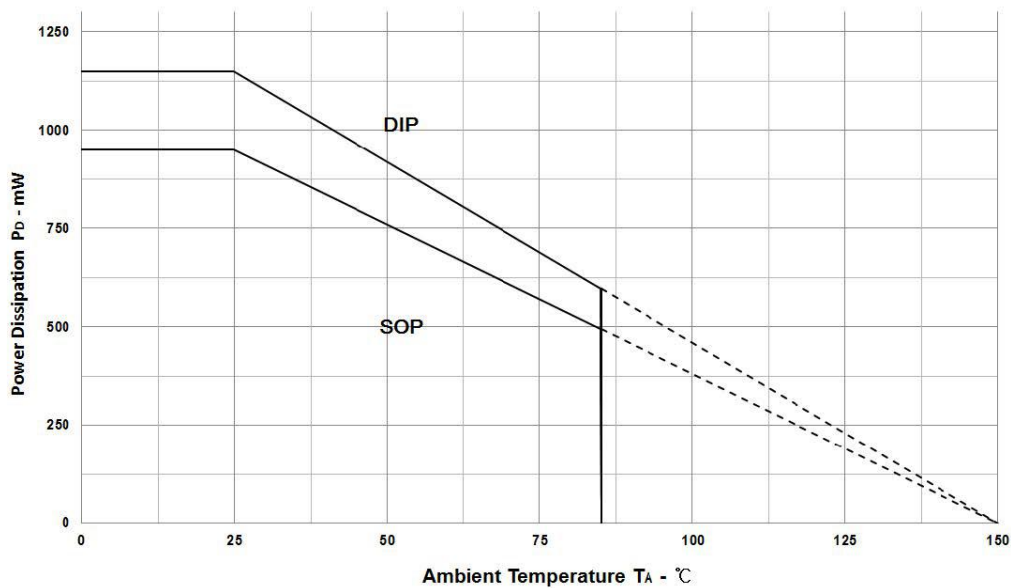


Figure 15

POWER DISSIPATION
VS.
AMBIENT TEMPERATURE



APPLICATION INFORMATION

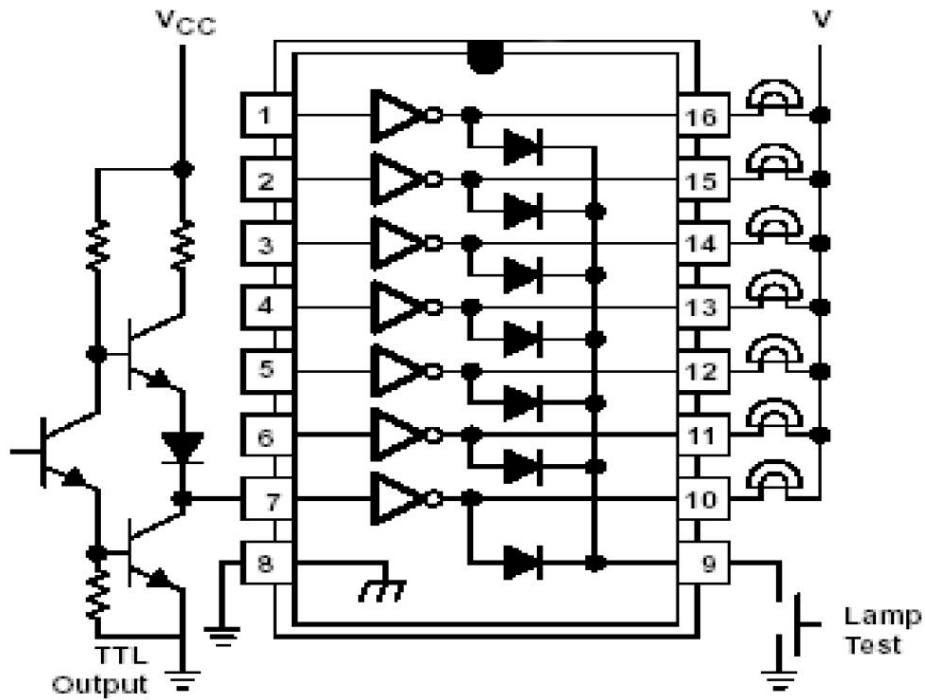


Figure 16. TTL to Load

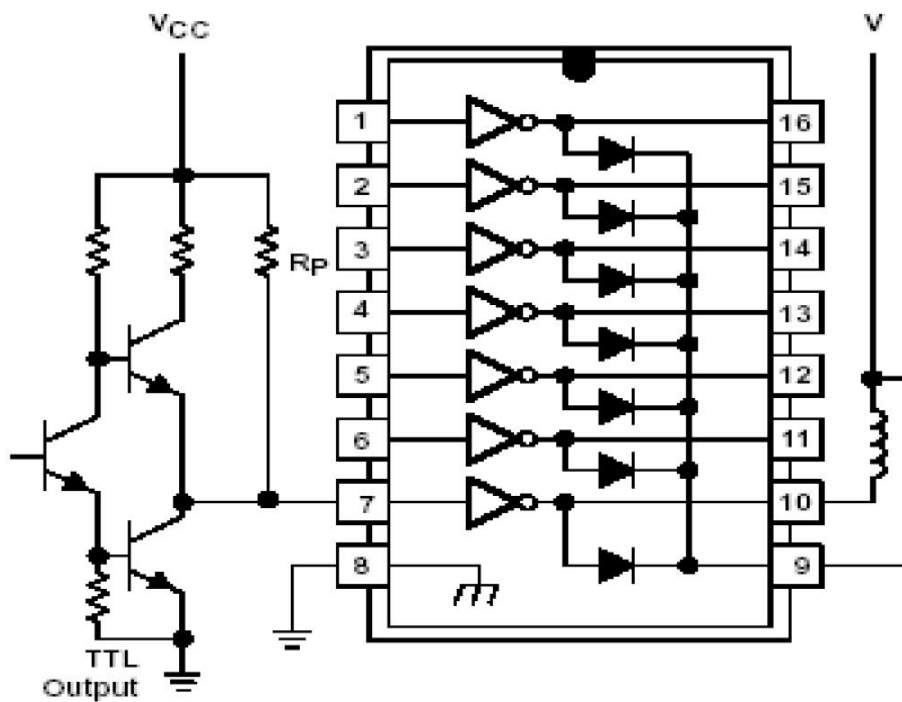
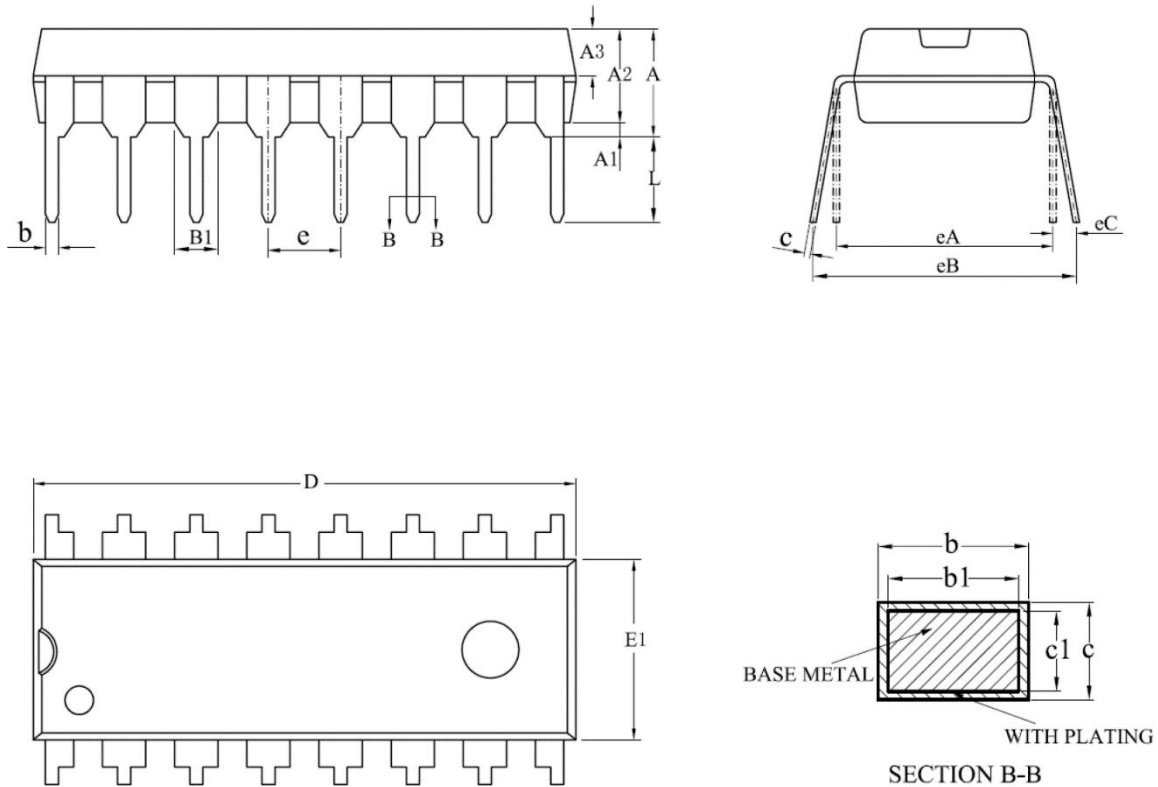


Figure 17. Use of Pullup Resistors to Increase Drive Current

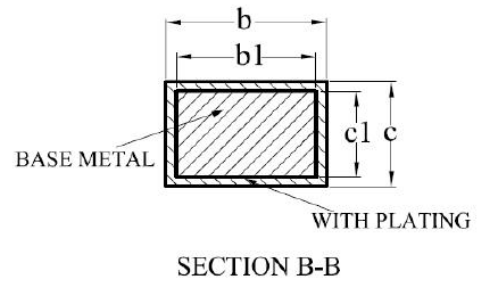
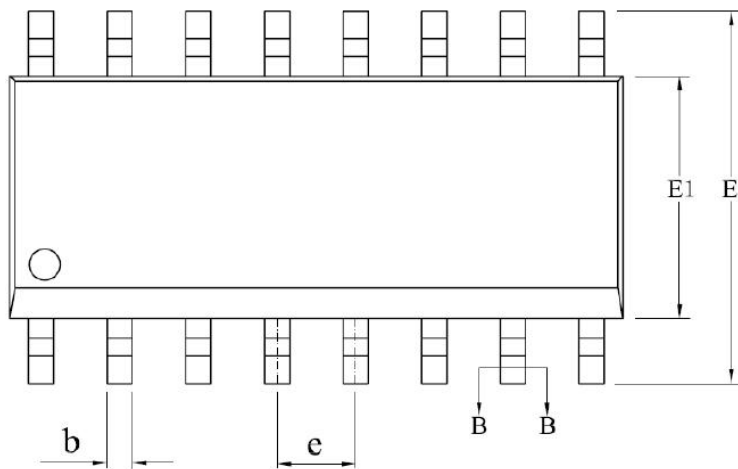
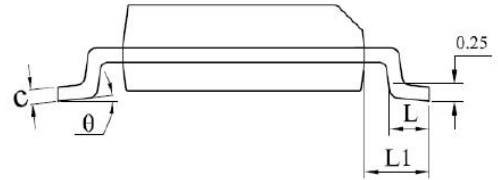
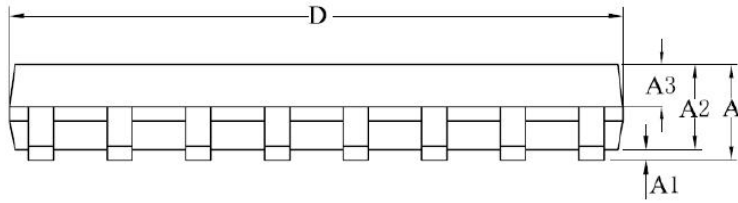
Package Dimensions

DIP-16



| SYMBOL | MILLIMETER | | | SYMBOL | MILLIMETER | | |
|----------------|------------|------|------|--------|------------|-------|-------|
| | MIN | NOM | MAX | | MIN | NOM | MAX |
| A | 3.60 | 3.80 | 4.00 | c1 | 0.24 | 0.25 | 0.26 |
| A1 | 0.51 | | | D | 18.90 | 19.10 | 19.30 |
| A2 | 3.10 | 3.30 | 3.50 | E1 | 6.15 | 6.35 | 6.55 |
| A3 | 1.42 | 1.52 | 1.62 | e | 2.54 BSC | | |
| b | 0.44 | | 0.53 | eA | 7.62 BSC | | |
| b1 | 0.43 | 0.46 | 0.48 | eB | 7.62 | | 9.50 |
| B1 | 1.52 BSC | | | eC | 0 | | 0.94 |
| c | 0.25 | | 0.31 | L | 3.00 | | |
| L/F 载体尺寸 (Mil) | 80×80 | | | | | | |
| | 110×140 | | | | | | |
| | 140×170 | | | | | | |

SOP-16



| SYMBOL | MILLIMETER | | | SYMBOL | MILLIMETER | | |
|----------------|------------|------|------|----------|------------|------|-------|
| | MIN | NOM | MAX | | MIN | NOM | MAX |
| A | | | 1.75 | D | 9.70 | 9.90 | 10.10 |
| A1 | 0.10 | | 0.25 | E | 5.80 | 6.00 | 6.20 |
| A2 | 1.35 | 1.40 | 1.45 | E1 | 3.70 | 3.90 | 4.10 |
| A3 | 0.60 | 0.65 | 0.70 | e | 1.27 BSC | | |
| b | 0.39 | | 0.48 | L | 0.50 | | 0.80 |
| b1 | 0.38 | 0.41 | 0.43 | L1 | 1.05 BSC | | |
| c | 0.21 | | 0.26 | θ | 0° | | 8° |
| c1 | 0.19 | 0.20 | 0.21 | | | | |
| L/F 载体尺寸 (Mil) | 75×75 | | | | | | |
| | 90×110 | | | | | | |
| | 70×180 | | | | | | |

PACKAGE/ORDERING INFORMATION

| PRODUCT | ORDERING | TEMPRANGE | PACKAGE | PAKEAGE | TRANSPOT |
|---------|------------|------------|---------|------------|--------------------|
| CBM2003 | CBM2003AS | -40°C~85°C | SOP-16 | CBM2003A | Tape and Reel,2500 |
| CBM2003 | CBM2003AIP | -40°C~85°C | DIP-16 | CBM2003AIP | Tape and Reel,50 |

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